



# UM10512

## SSL2109 reference board

Rev. 1.1 — 19 April 2012

User manual

### Document information

Info	Content
<b>Keywords</b>	SSL2109, buck, controller, reference board, LED driver, LED retrofit lamp
<b>Abstract</b>	This document describes the performance, technical data and the connection of the SSL2109 reference board. The SSL2109 is an NXP Semiconductors controller IC intended to provide a low cost, small form factor LED driver. The reference board is intended to operate at 230 V or 120 V (AC), using an output voltage of 30 V or greater.



Revision history

Rev	Date	Description
v.1.1	20120419	second issue
v.1	20120213	first issue

## 1. Introduction

### WARNING

#### Lethal voltage and fire ignition hazard



The non-insulated high voltages that are present when operating this product, constitute a risk of electric shock, personal injury, death and/or ignition of fire.

This product is intended for evaluation purposes only. It shall be operated in a designated test area by personnel qualified according to local requirements and labor laws to work with non-insulated mains voltages and high-voltage circuits. This product shall never be operated unattended.

### 1.1 Scope of this document

The SSL2109 is a highly integrated switching mode LED controller which enables Constant Current (CC) driving from the mains input. It is a solution for small to medium LED retrofit lamp application, especially for low-power factor design. The SSL2109 is a buck converter controller suitable for non-isolated, non-dimmable LED retrofit lamps. It can drive long LED strings with, typically 70 V forward voltages. The SSL2109 is intended to operate with higher output voltages, as in modern LED modules.

**Remark:** Unless otherwise stated all voltages are in V (AC).

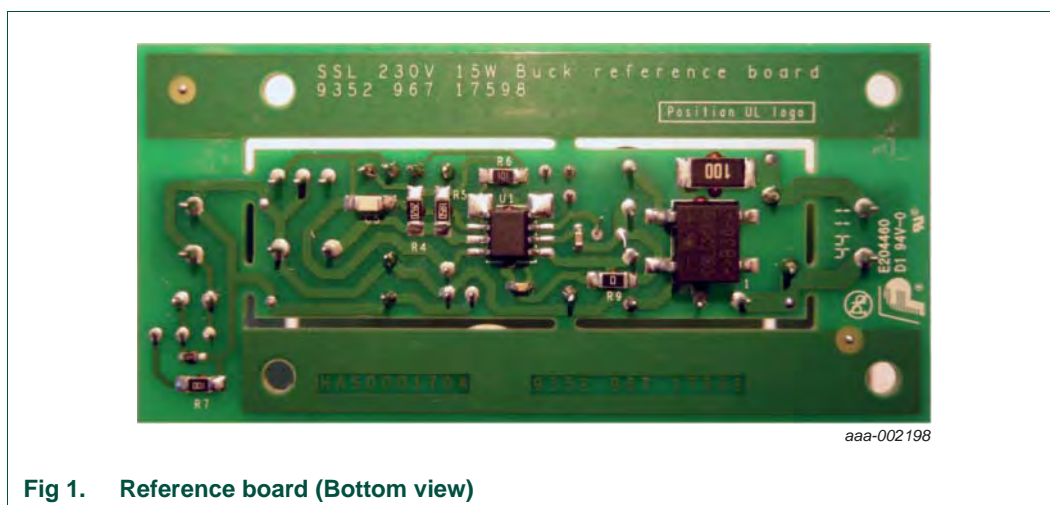


Fig 1. Reference board (Bottom view)



Fig 2. Reference board (Top view)

## 2. Safety warning

This reference board is connected to a high AC voltage. Avoid touching the reference board during operation. An isolated housing is mandatory when used in uncontrolled, non-laboratory environments. Galvanic isolation of the mains phase using a fixed or variable transformer (Variac) is always recommended. [Figure 3](#) shows the symbols on how to recognize these devices.

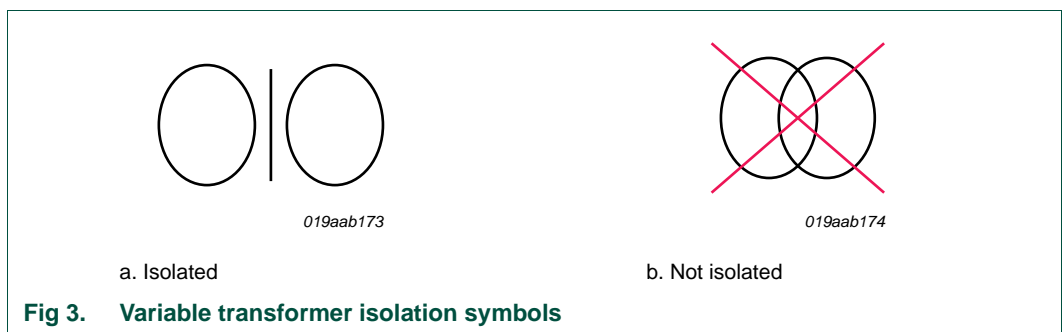


Fig 3. Variable transformer isolation symbols

## 3. Board connectivity

### 3.1 Connecting to the board

The board is optimized for a 230 V (50 Hz) or 120 V (50 Hz or 60 Hz) mains supply. In addition to the mains voltage optimization, the board is designed to work with multiple LEDs or an LED module with a high forward voltage. Mains connection of the reference board is different from other general evaluation/reference boards. Connect the mains to the screw connector J6.

**Remark:** The maximum rated voltage of the board is 400 V (DC) or 175 V (DC).

The anode of the LED load is connected to pin 1 of connector J5. The cathode is connected to pin 2 of connector J5. Use an LED string with a VF greater than 20 V on this reference board. Under the expected conditions, the output current is 200 mA. If the rated current of the LED does not meet the specification, the current can be adjusted. See [Section 6](#) for instructions.



## 4. Specification

Specifications for the reference board are listed in [Table 1](#)

**Table 1. Reference board specifications**

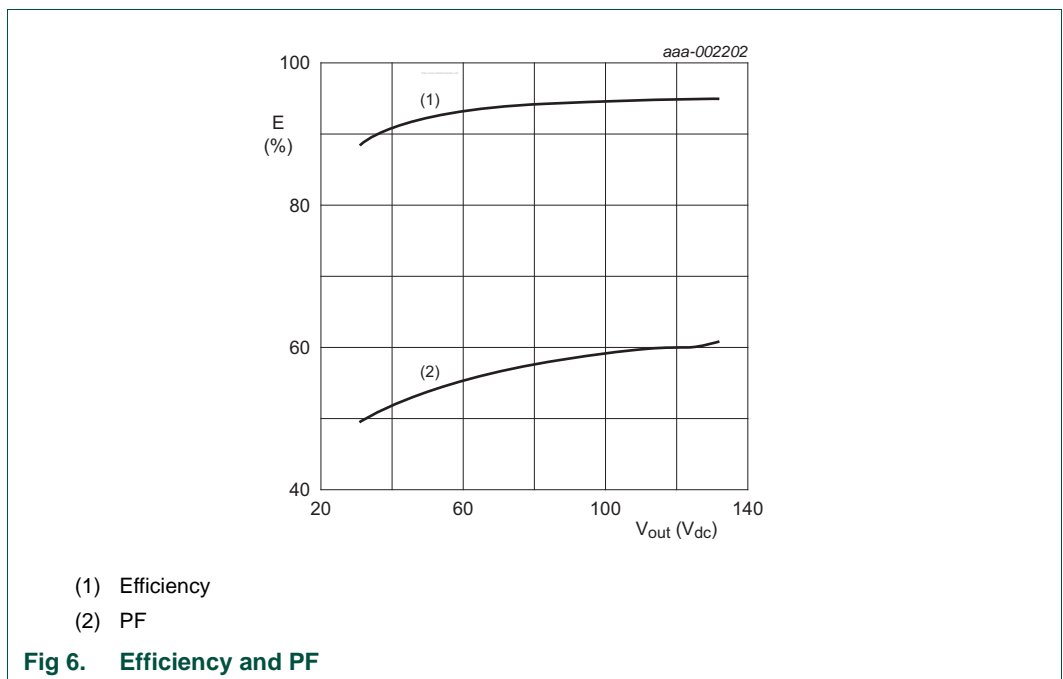
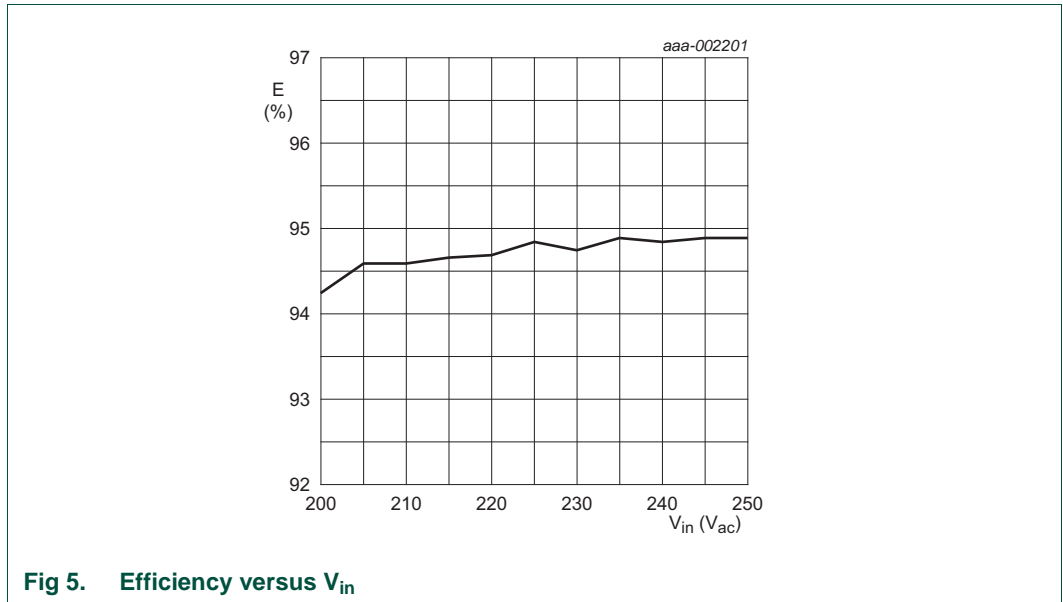
Parameter	Value	Comment
AC line input voltage	200 V to 250 V	Version 230 V 50 Hz
	100 V to 130 V	Version 120 V 60 Hz
Output voltage	30 V (DC) to 130 V (DC)	Version 230 V
	30 V (DC) to 90 V (DC)	Version 120 V
Output current	208 mA at $V_o = 100$ V (DC)	Version 230 V
	208 mA at $V_o = 70$ V (DC)	Version 120 V
Maximum power into LED load	23 W	-
Efficiency	>94 %	See <a href="#">Figure 5</a>
Power Factor	>0.5	at > 12 W
THD	83 %	at 20 W
Board dimensions (length x width x height, mm)	57 x 17.5 x 17.5	Internal board
	83 x 40	External board
Operating temperature	-40 °C to +100 °C	-
NTC Threshold temperature	80 °C	±15 °C

**Table 1. Reference board specifications**

Parameter	Value	Comment
Mains harmonics	IEC61000-3-2	$P_{out} > 13 \text{ W}$
EMC compliant	IEC55015	230 V model
	FCC15	120 V model
Surge testing	IEC61000-4-5	Level 3
Lifetime	26.000 hours	At $t_{amb} = 60 \text{ }^{\circ}\text{C}$

## 5. Performance data

Performance data is shown in [Figure 5](#) to [Figure 9](#)



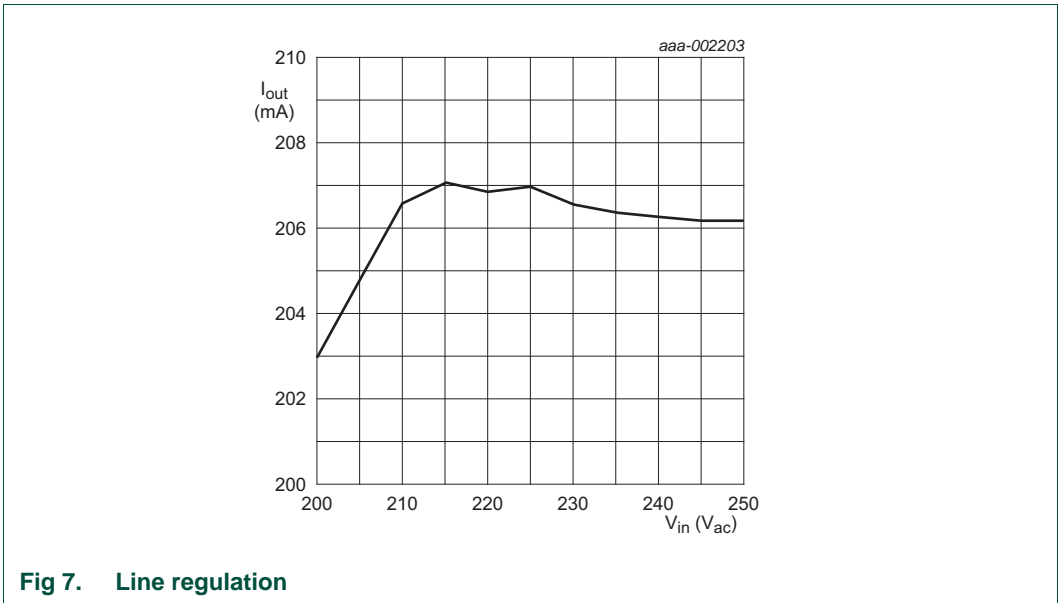


Fig 7. Line regulation

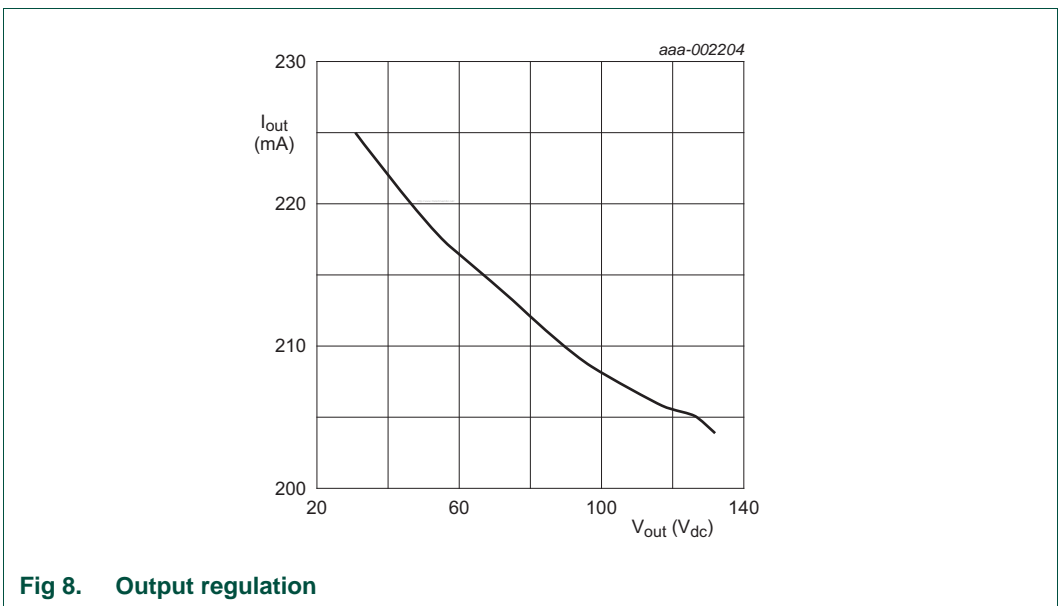


Fig 8. Output regulation



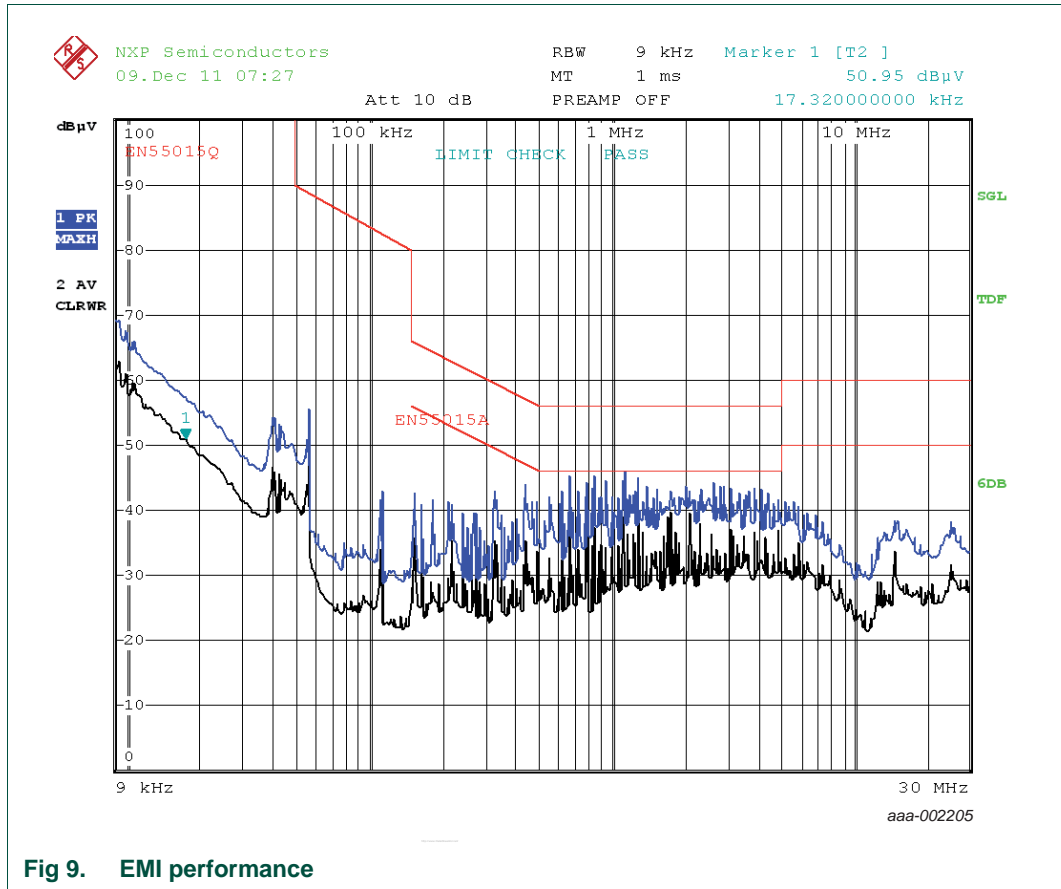


Fig 9. EMI performance

## 6. Changing the output current

The SSL2109 monitors the charging current in the inductor using the sense resistors R4 and R5. It controls a MOSFET to retain a constant peak current. In addition, the IC supports valley switching. These features enable a driver to operate in Boundary Conduction Mode (BCM) with valley switching where the average current in the inductor is the output current. The SSL2109 turns off the MOSFET when the voltage on pin SOURCE reaches 500 mV. If the value of R4 in parallel with R5 is 1, the peak current is limited to 500 mA. See [Equation 1](#)

$$I_{peak} = \frac{0.5 \times (R5 + R4)}{R5 \times R4} \tag{1}$$

When the MOSFET is turned off, inductor L2 is discharged and the current flowing through the inductor decreases. When the current in the inductor reaches 0 mA, the voltage on the DRAIN pin starts to oscillate due to the stray capacitance (ringing). The SSL2109 waits for a oscillation valley. The charge time of the inductor is calculated using [Equation 2](#)

$$t_{ch} = L2 \times \frac{2 \times I_{LED}}{V_I - V_{LED}} \tag{2}$$

The discharge time of the inductor is calculated using [Equation 3](#)

$$t_{dch} = L2 \times \frac{2 \times I_{LED}}{V_{LED}} \quad (3)$$

When the inductor is charging/discharging, a current flows through the inductor. However, there is also an effective current when ringing. Consider the oscillation frequency when adjusting the output current. It is calculated using [Equation 4](#)

$$f_{ring} = \frac{I}{2 \times \pi \times \sqrt{L2 \times (C_{FET} + C5)}} \quad (4)$$

The time from the start of oscillation to the first valley is calculated using [Equation 5](#)

$$t_{ring} = \frac{I}{2 \times f_{ring}} \quad (5)$$

The output current is calculated using [Equation 6](#). The resulting output current is:

$$I_{LED} = \frac{I}{2} \times I_{peak} \times \frac{t_{ch} + t_{dch}}{t_{ch} + t_{dch} + t_{ring}} \quad (6)$$

Therefore by changing  $I_{peak}$  we can change  $I_{LED}$ .

## 7. External OverTemperature Protection (OTP)

The SSL2109 supports external OTP by adding an external Negative Temperature Coefficient (NTC) resistor. This feature is delivered by detecting a voltage on pin NTC. The NTC pin has an integrated current source. The resistance of the NTC resistor is decreased as the temperature is increased. When the NTC temperature rises and the voltage on the NTC pin falls to less than 0.5 V, the SSL2109 lowers the threshold level for detecting peak current in the inductor. Decreasing the peak current in the inductor causes the power current to decrease. The output current is regulated to the point where a balance between temperature and output current can be retained (the so called thermal management).

If the temperature on NTC increases continuously and the voltage on the pin drops to less than 0.3 V, the SSL2109 starts the NTC time-out timer. If the voltage on the NTC pin does not drop to less than 0.2 V within the time-out, the SSL2109 detects an abnormal condition. As a result the SSL2109 stops switching. If the voltage reaches 0.2 V within the time-out period, a Pulse Width Modulation (PWM) signal is assumed.

An NTC resistor can be directly connected to the NTC pin. It is also possible to tune the protection temperature by adding a resistor in parallel or in series with the NTC. One NTC and one resistor are installed on the reference board. The values of these components can be changed depending on the protection temperature requirement and component availability.

Mounted the NTC in thermal contact with the LED string.

## 8. Power Factor (PF) adjustment

The SSL2109 IC and SSL2109 reference design is designed for standard operation

with a PF of 0.6 at 230 V. The choice offers the highest efficiency. It is possible to tune the PF to higher values using two methods.

Increasing the value of R1 raises the PF higher than 0.7 with additional losses. See [Table 2](#).

**Table 2. PF adjustment, increasing the value of resistor R1**

V <sub>I</sub> (V)	V <sub>O</sub> (V <sub>avr</sub> )	I <sub>O</sub> (mA)	R1 (Ω)	Efficiency (%)	PF	THD (%)
230	45	222	220	83.3	0.71	97
230	109	209	100	86.2	0.70	86
120	45	219	56	84.7	0.70	99
120	62	214	47	84.8	0.71	93

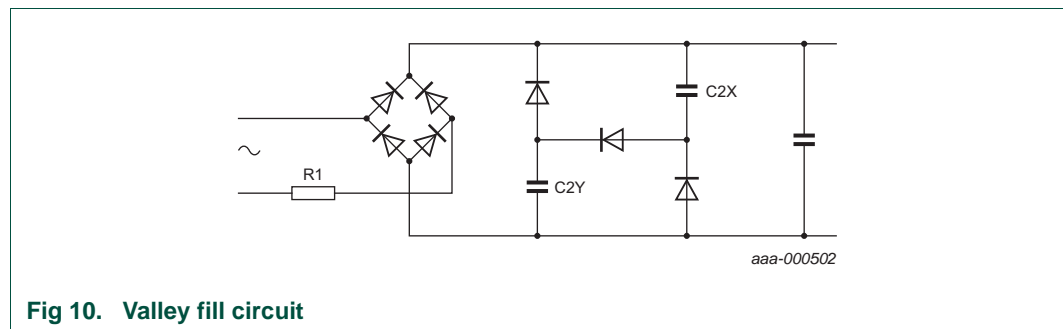
A resistor value of 220 W for R1 also results in operation with most available phase cut dimmers without damaging the lamp or dimmer. This change is not intended to reach stable operation without flicker or a good dimming range.

Dimension the power rating of R1 to handle peak powers that occur using leading-edge dimmers. These powers range between 2 W to 6 W. Alternatively, make a thermal link between the onboard NTC and R1, causing the board to turn off at overtemperature of R1.

The second option is to increase PF using a valley fill circuit. [Figure 10](#) shows the basic schematic for the circuit. [Table 3](#) shows the results.

**Table 3. PF adjustment, valley fill circuit**

V <sub>I</sub> (V)	V <sub>O</sub> (V <sub>avr</sub> )	I <sub>O</sub> (mA)	C2X/Y (μF)	L1 (mH)	R1 (Ω)	Efficiency (%)	PF	THD (%)
120	44.5	212	47	0.82	100	83.1	0.9	43
230	62	216	22	2.2	47	92.9	0.81	63
230	62	215	22	2.2	390	80	0.9	40



**Fig 10. Valley fill circuit**

The valley fill circuit can only be employed, if the output voltage is less than half the peak input voltage. At 230 V input, it operates up to 85 V (DC) output voltage, otherwise no power is delivered to the LEDs during the valley duration.

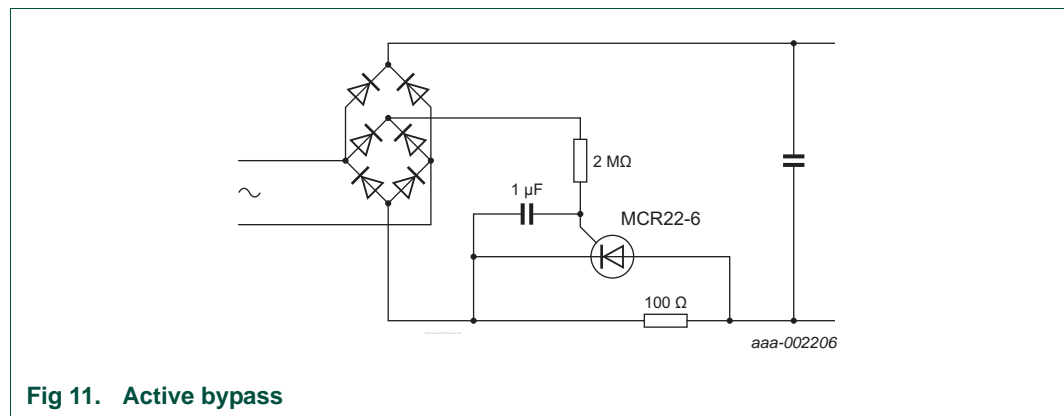
## 9. Active bypass

An increased value for the inrush current resistor protects the board from damage with phase cut dimmers, however lowers the efficiency. If a higher PF is not required, but leading-edge dimmer compatibility and high efficiency are important, the active bypass option is available. In this circuit, the inrush current resistor is bypassed using a Silicon Controlled Rectifier (SCR). See [Figure 11](#).

[Table 4](#) shows the results when active bypass is used.

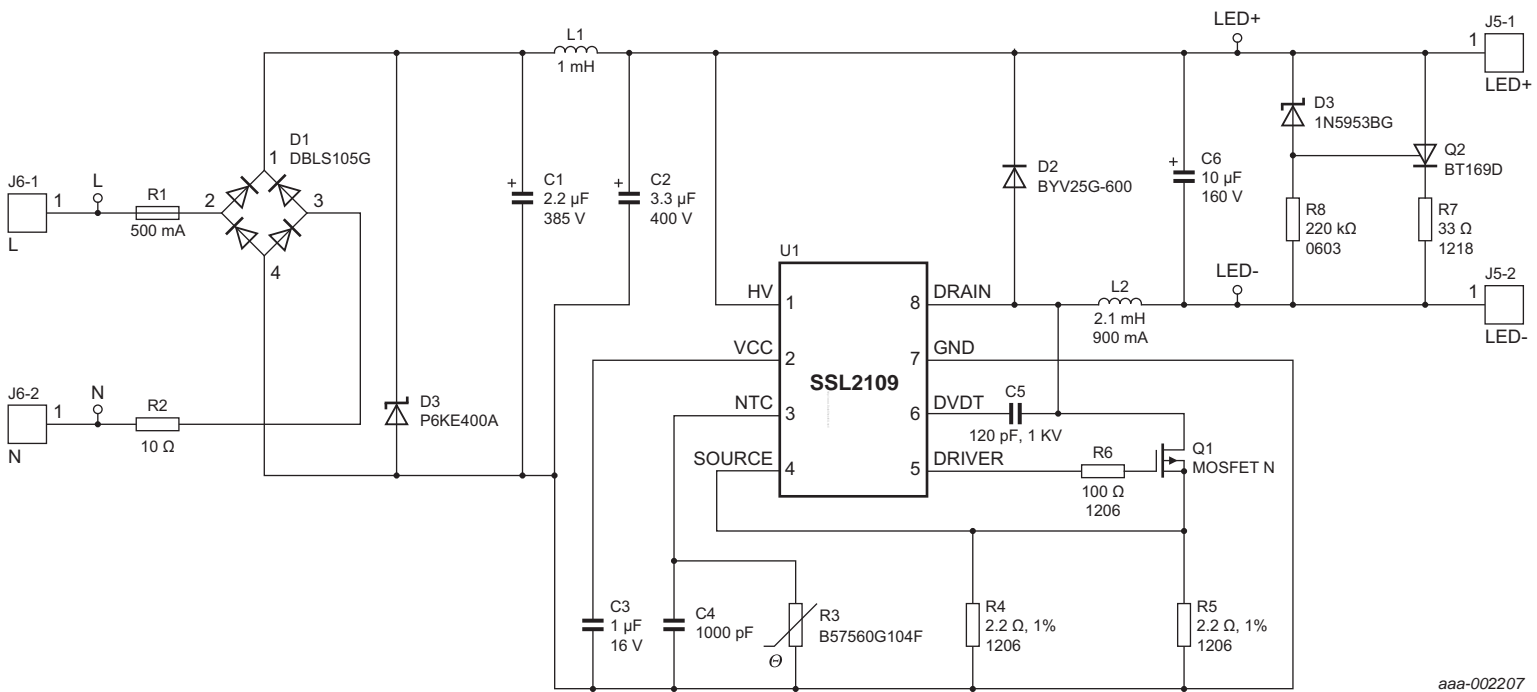
**Table 4. PF adjustment, valley circuit fill**

$V_I$ (V)	$V_O$ ( $V_{avr}$ )	$I_O$ (mA)	$R1$ ( $\Omega$ )	Efficiency (%)	PF	THD (%)
230	45	217	100	92.6	0.52	144
120	62	215	100	89.5	0.52	153



**Fig 11. Active bypass**

10. Schematic



aaa-002207

Fig 12. Reference board schematic

## 11. Bill Of Materials (BOM)

[Table 5](#) provides detailed component information for the SSL2109 reference board.

**Table 5. BOM for the high efficiency SSL2109 demo board**

Reference	Component	Package	Part number	Manufacturer
J6	connector 2 pin	-	MKDSN 2.5/2-5.08	Phoenix
J5	connector 2 pin	-	MKDSN 2.5/2-5.08	Phoenix
R1	fuse; 500 mA; 250 AC		0263.500HAT 1L	Littelfuse
R2	10 W; 2 W; 600 V; 5 %	2512	CRM2512-JW-100ELF	Bourns
R3	100 k $\Omega$ ;	-	B57560G104F	EPCOS
R4	2.2 W; 0.25 W; 200 V; 1 %	1206	RC1206FR-072R2L	Yageo
R5	2.2 W; 0.25 W; 200 V; 1 %	1206	RC1206FR-072R2L	Yageo
R6	100 W; 0.125 W; 200 V; 5 %	1206	MC0.125W12065% 100 R	Multicomp
R7	33 $\Omega$ ; 1 W; 200 V; 5 %	1218	PRC201 1218 33 R	Yageo
R8	220 k $\Omega$ ; 0.063 W; 50 V; 5 %	0603	MC0.063W0603 5 % 220 K	Multicomp
C1	2.2 $\mu$ F; 400 V; 20 %	8 $\times$ 11.5	ECA2GHG2R2	Panasonic
C2	3.3 $\mu$ F; 400 V; 20 %	10 $\times$ 12.5	ECA2GHG3R3	Panasonic
C3	1 $\mu$ F; 16 V; 10 %	0603	0603YC105KAT2A	AVX
C4	1 nF; 100 V; 10 %	0603	06031C102KAT2A	AVX
C5	120 pF; 1000 V; 5 %	1206	CC1206JKNPOCBN121	Yageo
C6	10 $\mu$ F; 105 $^{\circ}$ C; 160 V; 20 %	8 $\times$ 11.5	UVZ2C100MPD1TD	Nichicon
L1	1 mH; 10 %	-	768772102	Würth Elektronik
L2	2.1 mH; 10 %	RM6	750312626	Würth Elektronik
RV1	WE-VD; 275 V	10 mm	80412711	Würth Elektronik
Q1	3 A; 400 V; 1.5 $\Omega$	I-Pak	STD5NK40Z-1	ST Micro Electronics
Q2	0.8 A; 400 V	TO92	BT169D	NXP
D1	bridge; 1 A; 600 V	SOIC-4	DBLS105G	Multicomp
D2	5 A; 600 V	SOT226A	BYV25G-600	NXP
D4	Zener; 3 W; 150 V	DO-41	1N5953BG	On-semi
U1	IC; 600 V	SO8	SSL2109	NXP
<b>120 VAC</b>				
C1	10 $\mu$ F; 105 $^{\circ}$ C; 160 V; 20 %	8 $\times$ 11.5	UVZ2C100MPD1TD	Nichicon
C2	10 $\mu$ F; 105 $^{\circ}$ C; 160 V; 20 %	8 $\times$ 11.5	UVZ2C100MPD1TD	Nichicon
RV1	WE-VD; 130 V	10 mm	820511311	Würth Elektronik

## 12. Board layout

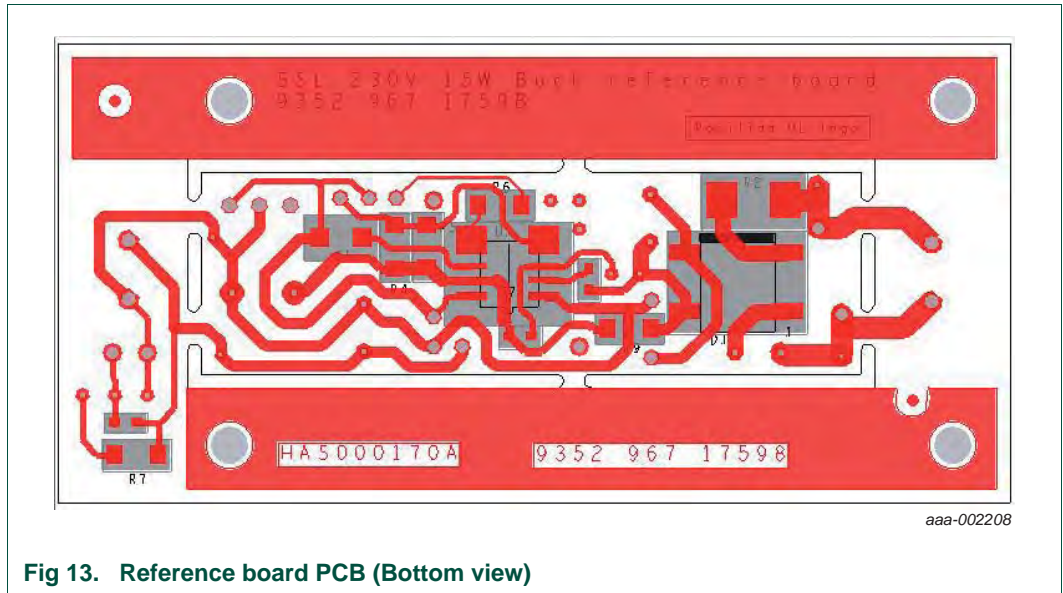


Fig 13. Reference board PCB (Bottom view)

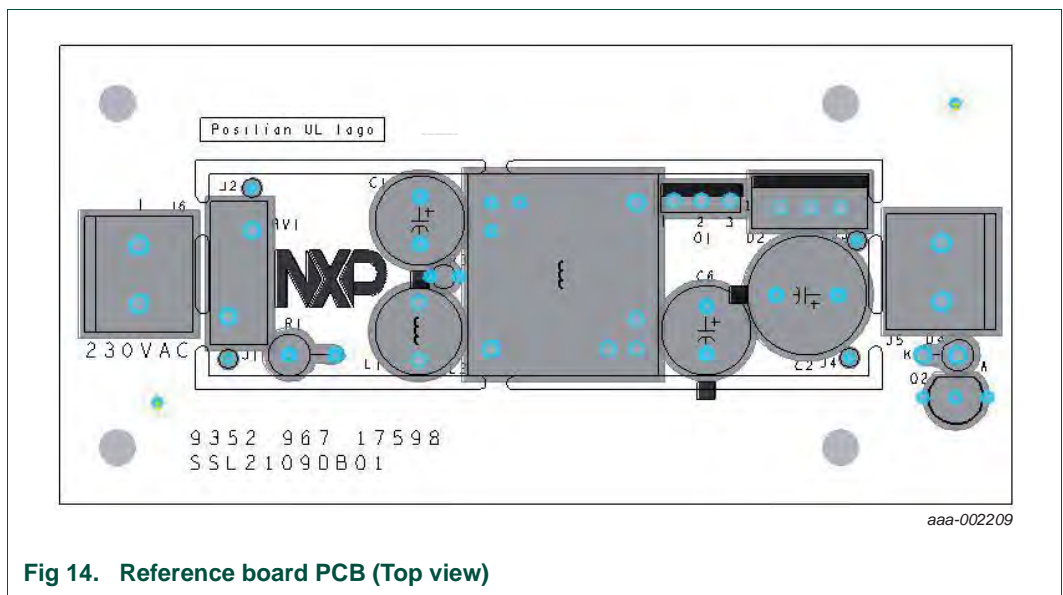


Fig 14. Reference board PCB (Top view)

13. Inductor specification

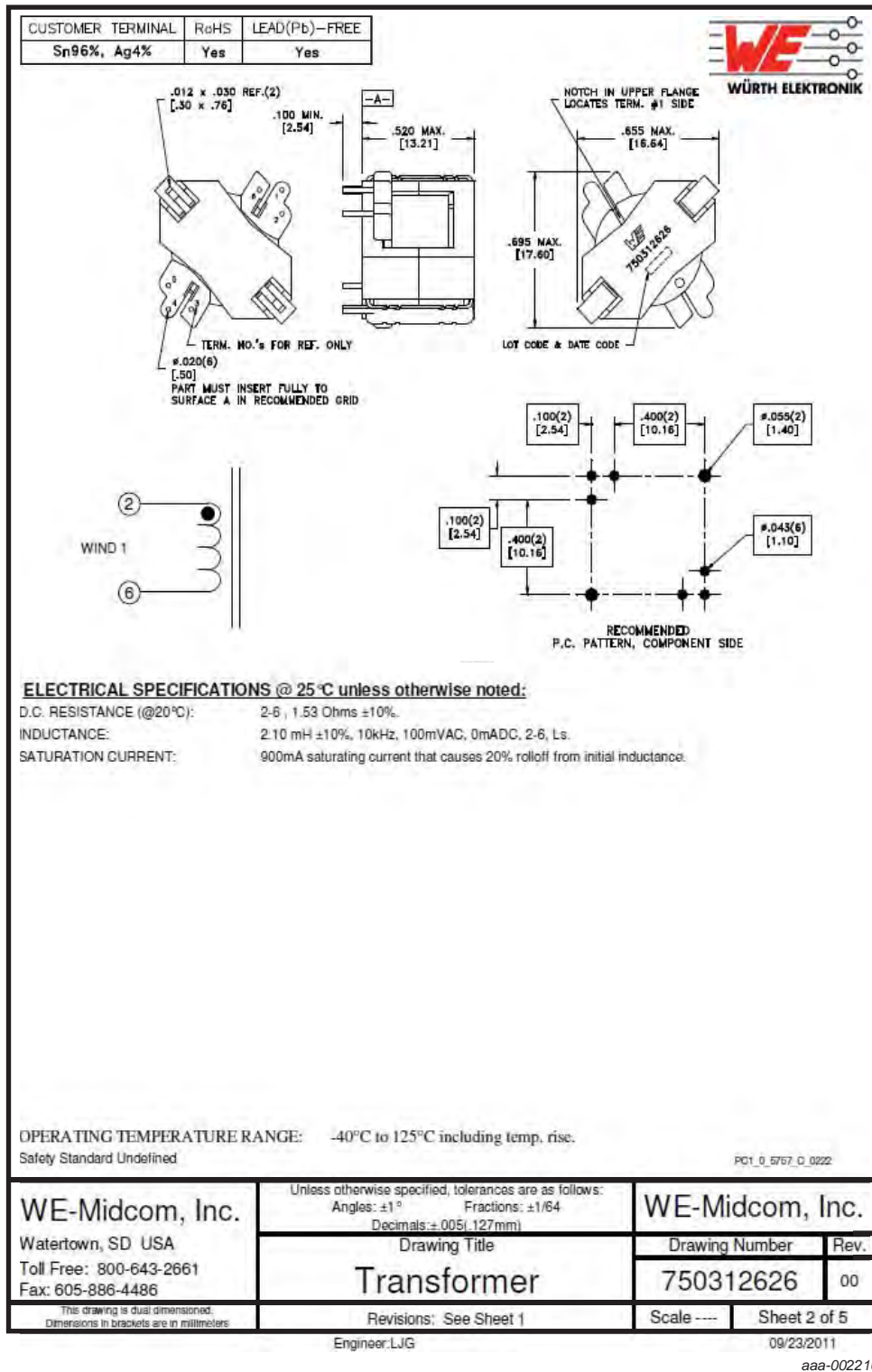


Fig 15. Inductor specification



## 14. Abbreviations

Table 6. Abbreviations

Acronym	Description
BCM	Boundary Conduction Mode
CC	Constant Current
DCM	Discontinuous Conduction Mode
EMC	ElectroMagnetic Compatibility
EMI	ElectroMagnetic Interference
LED	Light Emitting Diode
MOSFET	Metal-Oxide Semiconductor Field-Effect Transistor
NTC	Negative Temperature Coefficient
PF	Power Factor
PWM	Pulse-width Modulation
SCR	Silicon Controlled Rectifier

## 15. References

- [1] **SSL2108X** — Data sheet: Drivers for LED lighting
- [2] **AN11041** — Application Note: SSL2108X driver for SSL applications
- [3] **AN10876** — Application Note: Buck converter for SSL applications
- [4] **SSL2109** — Data sheet: SSL2109 reference board
- [5] **AN11136** — Application note: Buck convertor driver for SSL applications

## 16. Legal information

### 16.1 Definitions

**Draft** — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

### 16.2 Disclaimers

**Limited warranty and liability** — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. NXP Semiconductors takes no responsibility for the content in this document if provided by an information source outside of NXP Semiconductors.

In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of NXP Semiconductors.

**Right to make changes** — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

**Suitability for use** — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors and its suppliers accept no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

**Applications** — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using NXP Semiconductors products, and NXP Semiconductors accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NXP Semiconductors product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using NXP Semiconductors products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). NXP does not accept any liability in this respect.

**Safety of high-voltage evaluation products** — The non-insulated high voltages that are present when operating this product, constitute a risk of electric shock, personal injury, death and/or ignition of fire. This product is intended for evaluation purposes only. It shall be operated in a designated test area by personnel that is qualified according to local requirements and labor laws to work with non-insulated mains voltages and high-voltage circuits.

The product does not comply with IEC 60950 based national or regional safety standards. NXP Semiconductors does not accept any liability for damages incurred due to inappropriate use of this product or related to non-insulated high voltages. Any use of this product is at customer's own risk and liability. The customer shall fully indemnify and hold harmless NXP Semiconductors from any liability, damages and claims resulting from the use of the product.

**Export control** — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

**Evaluation products** — This product is provided on an "as is" and "with all faults" basis for evaluation purposes only. NXP Semiconductors, its affiliates and their suppliers expressly disclaim all warranties, whether express, implied or statutory, including but not limited to the implied warranties of non-infringement, merchantability and fitness for a particular purpose. The entire risk as to the quality, or arising out of the use or performance, of this product remains with customer.

In no event shall NXP Semiconductors, its affiliates or their suppliers be liable to customer for any special, indirect, consequential, punitive or incidental damages (including without limitation damages for loss of business, business interruption, loss of use, loss of data or information, and the like) arising out of the use of or inability to use the product, whether or not based on tort (including negligence), strict liability, breach of contract, breach of warranty or any other theory, even if advised of the possibility of such damages.

Notwithstanding any damages that customer might incur for any reason whatsoever (including without limitation, all damages referenced above and all direct or general damages), the entire liability of NXP Semiconductors, its affiliates and their suppliers and customer's exclusive remedy for all of the foregoing shall be limited to actual damages incurred by customer based on reasonable reliance up to the greater of the amount actually paid by customer for the product or five dollars (US\$5.00). The foregoing limitations, exclusions and disclaimers shall apply to the maximum extent permitted by applicable law, even if any remedy fails of its essential purpose.

### 16.3 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

**GreenChip** — is a trademark of NXP B.V.

## 17. Contents

<b>1</b>	<b>Introduction</b> .....	<b>3</b>
1.1	Scope of this document .....	3
<b>2</b>	<b>Safety warning</b> .....	<b>4</b>
<b>3</b>	<b>Board connectivity</b> .....	<b>4</b>
3.1	Connecting to the board .....	4
<b>4</b>	<b>Specification</b> .....	<b>5</b>
<b>5</b>	<b>Performance data</b> .....	<b>7</b>
<b>6</b>	<b>Changing the output current</b> .....	<b>9</b>
<b>7</b>	<b>External OverTemperature Protection (OTP)</b>	<b>10</b>
<b>8</b>	<b>Power Factor (PF) adjustment</b> .....	<b>10</b>
<b>9</b>	<b>Active bypass</b> .....	<b>12</b>
<b>10</b>	<b>Schematic</b> .....	<b>13</b>
<b>11</b>	<b>Bill Of Materials (BOM)</b> .....	<b>14</b>
<b>12</b>	<b>Board layout</b> .....	<b>15</b>
<b>13</b>	<b>Inductor specification</b> .....	<b>16</b>
<b>14</b>	<b>Abbreviations</b> .....	<b>17</b>
<b>15</b>	<b>References</b> .....	<b>17</b>
<b>16</b>	<b>Legal information</b> .....	<b>18</b>
16.1	Definitions .....	18
16.2	Disclaimers .....	18
16.3	Trademarks .....	18
<b>17</b>	<b>Contents</b> .....	<b>19</b>

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

© NXP B.V. 2012.

All rights reserved.

For more information, please visit: <http://www.nxp.com>

For sales office addresses, please send an email to: [salesaddresses@nxp.com](mailto:salesaddresses@nxp.com)

Date of release: 19 April 2012

Document identifier: UM10512